TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

T6C03

COLUMN AND ROW DRIVER FOR A DOT MATRIX LCD

The T6C03 is a 160-channel-output column and row driver for an STN dot matrix LCD.

The T6C03 features a 42-V LCD drive voltage and an 8-MHz maximum operating frequency. The T6C03 is able to drive LCD panels with a duty ratio of up to 1 / 480.

Features

 Display duty application : to 1 / 480 LCD drive signal : 160

 Data transfer : Column: 4 / 8-bit bidirectional Row: Single / Dual bidirectional

• Operating frequency $: 8 \text{ MHz} (V_{DD} = 5 \text{ V} \pm 10\%)$

 LCD drive voltage : 14 to 42 V Power supply voltage : 2.7 to 5.5 V : −20 to 75°C Operating temperature

LCD drive output resistance: 1.3 kΩ (max) (20 V, 1 / 13 bias)

 Display-off function : When / DSPOF is L, all LCD drive outputs (O1 to O160) remain at the V5 level.

: Cascade connection and auto enable transfer functions are available. Low power consumption

: EI / LP input enables LSI operation. EI / LP input

Connect EIO1 / 2 from the 1st LSI to L.

Unit: mm

| Т6С03 | LEAD | PITCH |
|-------|------|-------|
| 16005 | IN | OUT |
| (UA) | 0.8 | 0.14 |

Please contact with Toshiba or an authorized Toshiba dealer for information on package dimensions.

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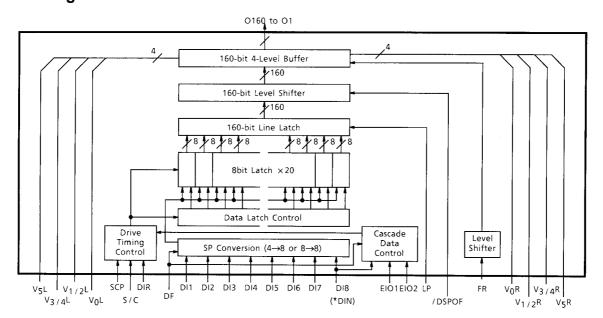
Light striking a semiconductor device generates electromotive force due to photoelectric effects. In some cases this can cause the device to malfunction.

This is especially true for devices in which the surface (back), or side of the chip is exposed. When designing circuits, make sure that devices are protected against incident light from external sources. Exposure to light both during regular operation and during inspection must be taken into account.

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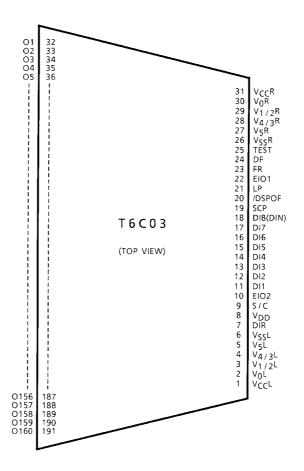
Block Diagram



* ROW MODE



Pin Assignment



Note: The above diagram shows the pin configuration of the LSI Chip, not that of the tape carrier package.



Pin Functions

| Pin Name | 1/0 | Functions | Level |
|------------|--------|--|------------------------------------|
| O1 to O160 | Output | Output for LCD drive signal | V ₀ to V ₅ |
| EIO1, EIO2 | 1/0 | (Column mode) Input / output for enable signal DIR selects In or Out. Connect EIO (IN) of 1st LSI to L. For a cascade connection, connect EIO (OUT) to EIO (IN) of next LSI. | |
| | | (Row mode) Input / output for shift data DIR = L : EIO1 is output, EIO2 is input DIR = H: EIO1 is input, EIO2 is output | |
| DI1 to DI8 | Input | (Column mode) Input for data signal | |
| סום סו דום | mput | (Row mode) DI1 to DI7: Fix to H or L, DI8: when DF = H, use as DIN | |
| DIR | Input | (Direction) Input for data flow direction select | |
| / DSPOF | Input | (Display off) / DSPOF = L : Display-off mode, (O1 to O160) remain at the V ₅ level / DSPOF = H: Display-on mode, (O1 to O160) are operational. | |
| DF | Input | (Data format) Input for data bit select | V _{DD} to V _{SS} |
| LP | Input | (Latch pulse) Display data is latched on falling edges of LP. When EIO (IN) = L, SCP · LP = H enables the 1st LSI. | |
| | | (Row mode) Input for shift clock pulse | |
| FR | Input | (Frame) Input for frame signal | |
| SCP | Input | (Column mode) Input for shift clock pulse | |
| - 50F | iliput | (Row mode) Fix to H or L | |
| TEST | Input | (TEST) Fix to L | |
| S/C | Input | Input for mode select: H = Column mode, L = Row mode | |



| Pin Name | 1/0 | Functions | Level |
|---|-----|--|-------|
| V_{DD} | _ | Power supply for internal logic (+5.0 V) | |
| V _{SS} | _ | Power supply for internal logic (0 V) | |
| V ₅ L · R | _ | Power supply for LCD drive circuit | |
| V _{3/4} L·R | _ | Power supply for LCD drive circuit | _ |
| V _{2 / 1} L · R | _ | Power supply for LCD drive circuit | |
| V ₀ L · R | _ | Power supply for LCD drive circuit | |
| V _{CC} L · R, V _{SS} L · R | _ | Power supply for LCD drive circuit | |

Relation Between FR, Data Input and Output Level

| FR | Data Input | / Dspof | Output Level (Column Mode) | Output Level (Row Mode) |
|--------|------------|---------|-------------------------------|----------------------------|
| L | L | Н | V ₃ | V ₄ |
| L | Н | Н | V ₅ | V ₀ |
| Н | L | Н | V ₂ | V ₁ |
| Н | Н | Н | V ₀ | V ₅ |
| (Note) | (Note) | L | V ₅ | V ₅ |

Note: Don't Care



Data Input Format

Column Mode

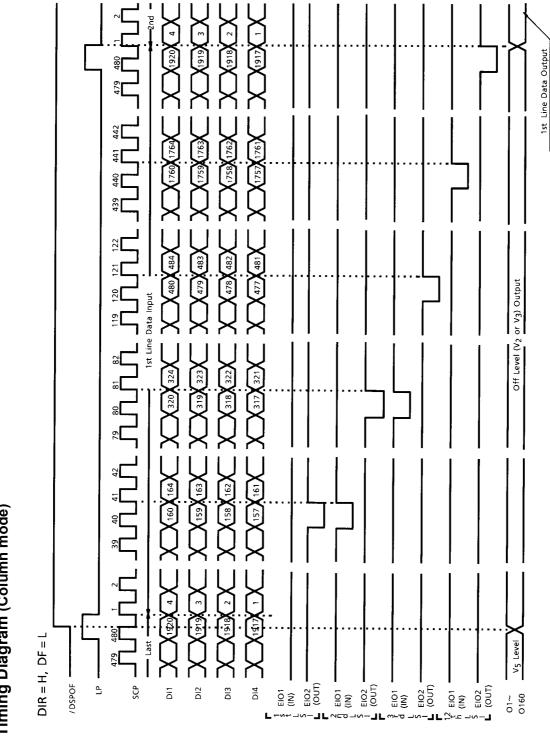
| DID | DE | DIT Mada | Enab | le Pin | (NI=4= 4) | | | Input Da | ta Line a | nd Outpu | t Buffers | | | | | | | |
|-----|-----|----------|------|--------|-----------|------|------|----------|-----------|----------|-----------|------|------|------|------|------|------|---|
| DIR | DF | BIT Mode | EIO1 | EIO2 | (Note 1) | DI1 | DI2 | DI3 | DI4 | DI5 | DI6 | DI7 | DI8 | | | | | |
| Н | | | IN | OUT | L | O160 | O159 | O158 | O157 | _ | _ | _ | _ | | | | | |
| | , | 4-BIT | 114 | 001 | F | 04 | О3 | O2 | 01 | ı | ı | 1 | | | | | | |
| | L | 4-DII | OUT | OUT | OUT | OUT | OUT | OUT | IN | L | 01 | 02 | О3 | 04 | _ | _ | _ | _ |
| L . | | | 001 | 114 | F | O157 | O158 | O159 | O160 | _ | _ | _ | _ | | | | | |
| Н | | | INI | INI | INI | IN | INI | OUT | L | O160 | O159 | O158 | O157 | O156 | O155 | O154 | O153 | |
| '' | Н | 8-BIT | IIN | 001 | F | O8 | 07 | O6 | O5 | 04 | О3 | O2 | 01 | | | | | |
| | OUT | | L | 01 | O2 | О3 | 04 | O5 | O6 | 07 | 08 | | | | | | | |
| L | | | 001 | IIN | F | O153 | O154 | O155 | O156 | O157 | O158 | O159 | O160 | | | | | |

Note 1: L: Last Data F: First Data

Row Mode

| DID | 5.5 | Data Flow | Data Input Terminals | | | |
|-----|--------|------------------------|----------------------|------|-----|--|
| DIR | DIR DF | | EIO1 | EIO2 | DIN | |
| L | 1 | O160 → O1 | OUT | IN | _ | |
| Н | L | O1 → O160 | IN | OUT | _ | |
| L | Н | O160 → O81 O80 → O1 | OUT | IN | IN | |
| Н | 11 | O1 → O80 O81 → O160 | IN | OUT | IN | |

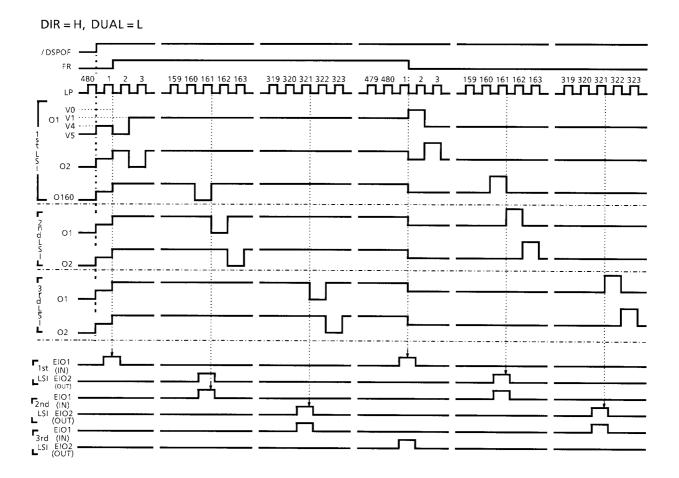
Timing Diagram (Column mode)



T6C03-7



Timing Diagram (Row mode)





Absolute Maximum Ratings

(Ensure that the following conditions are maintained, $V_{CC} \ge V_0 \ge V_2 \ge V_3 \ge V_5 \ge V_{SS}$)

| Item | Symbol | Pin Name | Rating | Unit |
|-----------------------|---------------------------------|---|-------------------------------|------|
| Supply Voltage (1) | V_{DD} | V_{DD} | -0.3 to 7.0 | V |
| Supply Voltage (2) | V _{CC} | V _{CCL} /R | -0.3 to 45.0 | V |
| Supply Voltage (3) | V ₀ , V ₂ | V _{0L / R} V _{2L / R} | -0.3 to V _{CC} + 0.3 | V |
| Supply Voltage (4) | V ₃ , V ₅ | V _{3L / R} V _{5L / R} | -0.3 to 7.0 | ٧ |
| Input Voltage | V _{IN} | (Note 2) | -0.3 to V _{DD} + 0.3 | V |
| Operating Temperature | T _{opr} | _ | −20 to 75 | °C |
| Storage Temperature | T _{stg} | _ | -40 to 125 | °C |

Note 2: SCP, FR, LP, DIR, DF, S / C, EIO1, EIO2, DI1 to 8, / DSPOF, TEST

Electrical Characteristics DC Characteristics

(Unless otherwise noted, $V_{SS} = 0 \text{ V}$, $V_{DD} = 2.7 \text{ to } 5.5 \text{ V}$, $Ta = -20 \text{ to } 75^{\circ}\text{C}$)

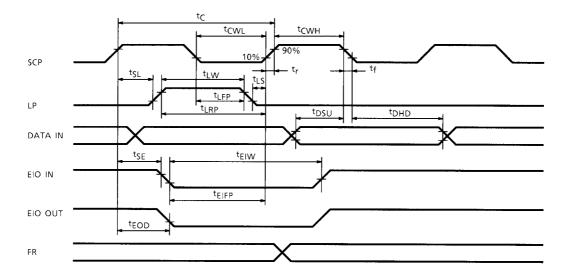
| Ite | m | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit | Pin Name | |
|---------------------------------|-----------|-----------------|-----------------|--|--------------------------|------|------------------------|------|--|--|
| Supply Volta | age 1 | V_{DD} | _ | _ | 2.7 | 5.0 | 5.5 | | V_{DD} | |
| Supply Volta | age 2 | V _{CC} | _ | _ | 14 | _ | 42 | | V _{CCL} / R | |
| Input | H Level | V_{IH} | _ | (Note 2) | 0.8 V _{DD} | ı | V_{DD} | | SCP, FR, LP, DIR, DF, S / C, EIO1, EIO2, | |
| Voltage | L Level | V_{IL} | _ | (Note 2) | 0 | _ | 0.2 V _{DD} | V | DI1 to 8, / DSPOF, TEST | |
| Output Voltage | H Level | V _{OH} | _ | I _{OH} = - 0.5 mA | V _{DD} - 0.5 | ı | V _{DD} | | EIO1, EIO2 | |
| Voltage | L Level | V_{OL} | _ | I_{OL} = 0.5 mA | 0 | _ | 0.5 | | | |
| | H Level | R _{OH} | _ | $V_{OUT} = V_0 - 0.5 V$ (Note 3) | _ | 0.6 | 1.3 | | | |
| Output | M Level | Pou | _ | $V_{OUT} = V_2 \pm 0.5 \text{ V}$ (Note 3) | _ | 0.6 | 1.3 | kΩ | O1 to O160 | |
| Resistance | IVI LEVEI | R _{OM} | _ | $V_{OUT} = V_3 \pm 0.5 \text{ V}$ (Note 3) | _ | 0.6 | 1.3 | K12 | 01 10 0 100 | |
| | L Level | R _{OL} | _ | $V_{OUT} = V_5 + 0.5 V$ (Note 3) | _ | 0.6 | 1.3 | | | |
| Current Consumption (Note 4) | | I _{DD} | _ | $\begin{split} &V_{DD}=5.5\text{ V}\\ &V_{CC}=42\text{ V}\\ &f_{LP}=33\text{ kHz}\\ &f_{FR}=8.3\text{ kHz}\\ &f_{scp}=8.0\text{ MHz}\\ &\text{Input Data: every bit inverted}\\ &V_{IH}=5.5\text{ V}, V_{IL}=0\text{ V} \end{split}$ | _ | _ | 4.0 | mA | V _{DD} | |

Note 3: $V_{CC} = 20 \text{ V}$, 1 / 13 bias

Note 4: Current consumption while the internal data receiver is operating



AC Electrical Characteristics (Column mode)



Test Conditions (1) (V_{SS} = 0 V, V_{DD} = 5 V \pm 10%, V_{CC} = 14 to 42 V, Ta = - 20 to 75°C)

| Item | Symbol | Test Condition | Min | Max | Unit |
|-----------------------|-------------------------------------|----------------|-----|----------|------|
| Clock Cycle | t _C | _ | 125 | _ | ns |
| SCP Pulse Width | t _{CWH} , t _{CWL} | _ | 50 | _ | ns |
| Data Set-Up Time | t _{DSU} | _ | 50 | _ | ns |
| Data Hold Time | t _{DHD} | _ | 50 | _ | ns |
| SCP Rise / Fall Time | t _r , t _f | _ | _ | (Note 5) | ns |
| LP Rise Time | t _{LRP} | _ | 50 | _ | ns |
| LP Fall Time | t _{LFP} | | 50 | _ | ns |
| LP Pulse Width | t _{LW} | _ | 45 | _ | ns |
| SCP-to-LP Delay Time | t _{SL} | | 40 | _ | ns |
| LP-to-SCP Delay Time | t _{LS} | | 40 | _ | ns |
| EIO IN Fall Time | t _{EIFP} | | 40 | _ | ns |
| EIO IN Pulse Width | t _{EIW} | _ | 40 | _ | ns |
| SCP-to-EIO Delay Time | t _{SE} | - | 20 | _ | ns |
| EIO-OUT Delay Time | t _{EOD} | (Note 6) | _ | 80 | ns |

Note 5: t_r , $t_f \le (t_C - t_{CWH} - t_{CWL}) / 2$ and t_r , $t_f \le 50$ ns

Note 6: $C_L = 30 pF$



Test Conditions (2) (V_{SS} = 0 V, V_{DD} = 2.7 to 4.5 V, V_{CC} = 14 to 42 V, Ta = -20 to 75°C)

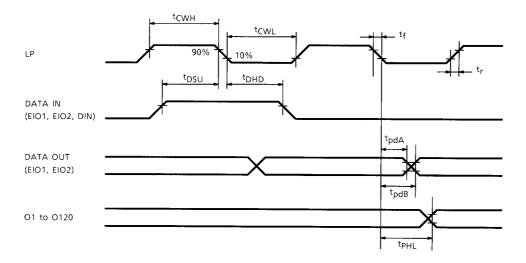
| Item | Symbol | Test Condition | Min | Max | Unit |
|-----------------------|-------------------------------------|----------------|-----|----------|------|
| Clock Cycle | t _C | _ | 500 | _ | ns |
| SCP Pulse Width | t _{CWH} , t _{CWL} | _ | 240 | _ | ns |
| Data Set-Up Time | t _{DSU} | _ | 240 | _ | ns |
| Data Hold Time | t _{DHD} | _ | 240 | _ | ns |
| SCP Rise / Fall Time | t _r , t _f | _ | _ | (Note 7) | ns |
| LP Rise Time | t _{LRP} | _ | 220 | _ | ns |
| LP Fall Time | t _{LFP} | _ | 240 | _ | ns |
| LP Pulse Width | t _{LW} | _ | 240 | _ | ns |
| SCP-to-LP Delay Time | t _{SL} | _ | 70 | _ | ns |
| LP-to-SCP Delay Time | t _{LS} | _ | 100 | _ | ns |
| EIO IN Fall Time | t _{EIFP} | _ | 240 | _ | ns |
| EIO IN Pulse Width | t _{EIW} | _ | 240 | _ | ns |
| SCP-to-EIO Delay Time | tsE | _ | 50 | _ | ns |
| EIO-OUT Delay Time | t _{EOD} | (Note 8) | _ | 260 | ns |

Note 7: t_r , $t_f \le (t_C - t_{CWH} - t_{CWL}) / 2$ and t_r , $t_f \le 50$ ns

Note 8: $C_L = 30 pF$



AC Electrical Characteristics (Row mode)



Test Conditions (1) ($V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, V_{CC} = 14 \text{ to } 42 \text{ V}, Ta = -20 \text{ to } 75^{\circ}\text{C}$)

| Item | | Symbol | Test Condition | Min | Max | Unit |
|---------------------------|-----------|---------------------------------|-------------------------|-----|-----|------|
| LP Pulse Width H | | t _{CWH} | LP | 30 | _ | ns |
| LP Pulse Width L | | t _{CWL} | LP | 195 | _ | ns |
| SCP Rise / Fall Time | | t _r , t _f | LP, FR, EIO1, EIO2, DIN | _ | 20 | ns |
| Data Set-up Time | | t _{DSU} | EIO1, EIO2, DIN | 80 | _ | ns |
| Data Hold Time | | t _{DHD} | EIO1, EIO2, DIN | 0 | _ | ns |
| EIO-OUT Delay Time A | (Note 9) | t _{pdA} | EIO1, EIO2, DIN | 5 | _ | ns |
| EIO-OUT Delay Time A | (Note 9) | t _{pdB} | EIO1, EIO2, DIN | _ | 150 | ns |
| LCD Drive Data Delat Time | (Note 10) | t _{PHL} | O1 to O120 | _ | 800 | ns |

Test Conditions (2) (V_{SS} = 0 V, V_{DD} = 2.7 to 5.5 V, V_{CC} = 14 to 42 V, Ta = -20 to 75°C)

| Item | | Symbol | Test Condition | Min | Max | Unit |
|---------------------------|-----------|---------------------------------|-------------------------|-----|------|------|
| LP Pulse Width H | | tcwH | LP | 100 | _ | ns |
| LP Pulse Width L | | t _{CWL} | LP | 400 | _ | ns |
| SCP Rise / Fall Time | | t _r , t _f | LP, FR, EIO1, EIO2, DIN | _ | 20 | ns |
| Data Set-up Time | | t _{DSU} | EIO1, EIO2, DIN | 100 | _ | ns |
| Data Hold Time | | t _{DHD} | EIO1, EIO2, DIN | 0 | _ | ns |
| EIO-OUT Delay Time A | (Note 9) | t _{pdA} | EIO1, EIO2, DIN | 5 | _ | ns |
| EIO-OUT Delay Time A | (Note 9) | t _{pdB} | EIO1, EIO2, DIN | _ | 400 | ns |
| LCD Drive Data Delat Time | (Note 10) | t _{PHL} | O1 to O120 | _ | 1000 | ns |

Note 9: $C_L = 30 \text{ pF}$ Note 10: $C_L = 20 \text{ pF}$

Note: Insert the bypass capacitor (0.1 μF) between V_{DD} and V_{SS} , to decrease power supply noise.

Place the bypass capacitor as close to the LSI as possible.

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